**WNSC2D30650W** 



### Silicon Carbide Diode Rev.01 - 27 January 2022

**Product data sheet** 

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Rohs

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## **1. General description**

Silicon Carbide Schottky diode in a 2-lead TO247-2L plastic package, designed for high frequency switched-mode power supplies.

## 2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- High Forward Surge Capability I<sub>FSM</sub>
- · Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

## 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

## 4. Quick reference data

<u> </u>			Values				
Symbol	Parameter	Conditions	Values		Unit		
Absolute	maximum rating						
$V_{RRM}$	repetitive peak reverse voltage			6	50		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 102 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		30		A	
T <sub>j</sub>	junction temperature			175		°C	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.7	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.75	2.1	V
Dynamic	characteristics						
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 30 A; dI <sub>F</sub> /dt = 500 A/μs; V <sub>R</sub> = 400 V; T <sub>i</sub> = 25 °C; <u>Fig. 7</u>		-	48	-	nC

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	А	anode		K — A 001aaa020
mb	mb	mounting base; connected to cathode	Г. Г	

## 6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WNSC2D30650W	TO247-2L	WNSC2D30650WQ	Tube	30	TO247L-2L	10-Nov-2020		

# 7. Marking

Table 4. Marking codes						
Type number	Marking codes					
WNSC2D30650W	WNSC2D 30650W					

2alk15-002

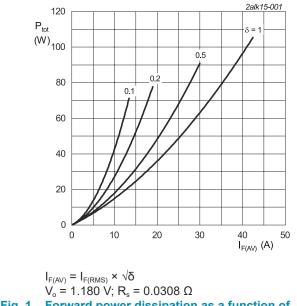
## 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{\text{RRM}}$	repetitive peak reverse voltage		650	V
V <sub>RWM</sub>	crest working reverse voltage		650	V
V <sub>R</sub>	reverse voltage	DC	650	V
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; T <sub>mb</sub> ≤ 102 °C; Fig. 1; Fig. 2; Fig. 3	30	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 102 °C; square-wave pulse	30	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	155	А
	forward current	$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	1200	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms	120	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature		-55 to 175	°C
T <sub>j</sub>	junction temperature		175	°C

250



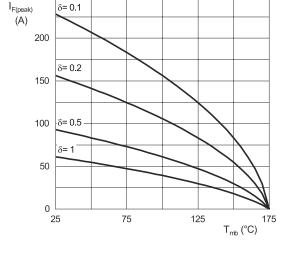
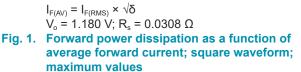


Fig. 2. Current derating as a function of mounting base temperature



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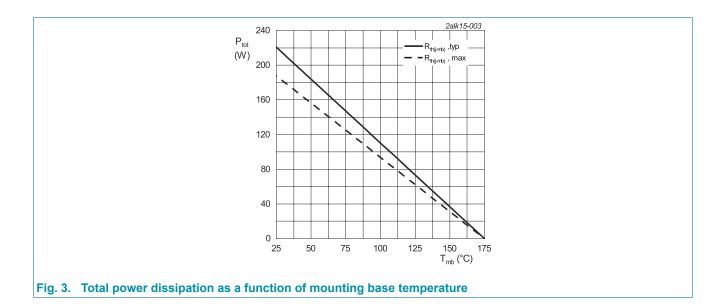
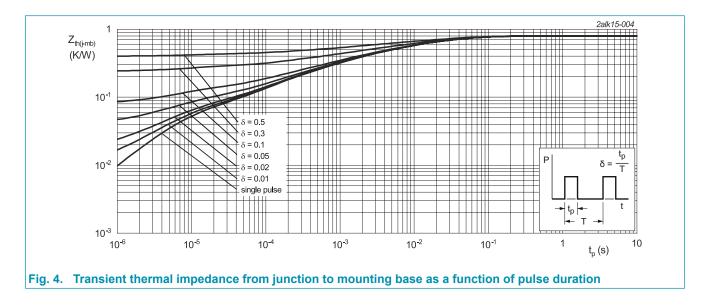


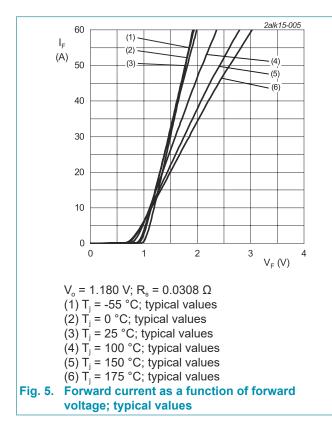
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig. 4		-	0.68	0.8	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

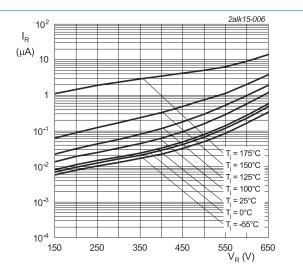
## 9. Thermal characteristics



## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V <sub>F</sub>	forward current	I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.45	1.7	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.75	2.1	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>	-	1.85	2.4	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	5	100	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>	-	35	200	μA
Dynamic	characteristics					
Q <sub>r</sub>	recovered charge	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	48	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	980	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C	-	105	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	100	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 6.3 A; L = 5 mH; T <sub>j(init)</sub> = 25 °C	99	-	-	mJ



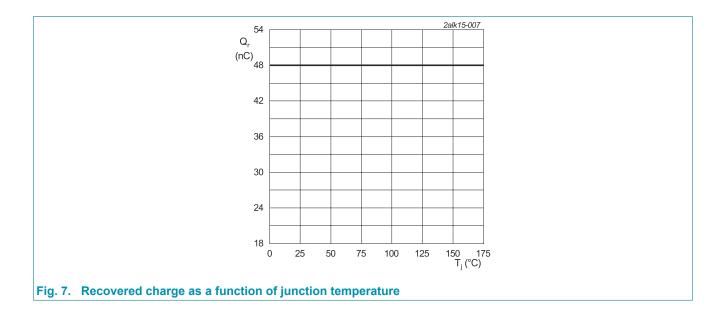




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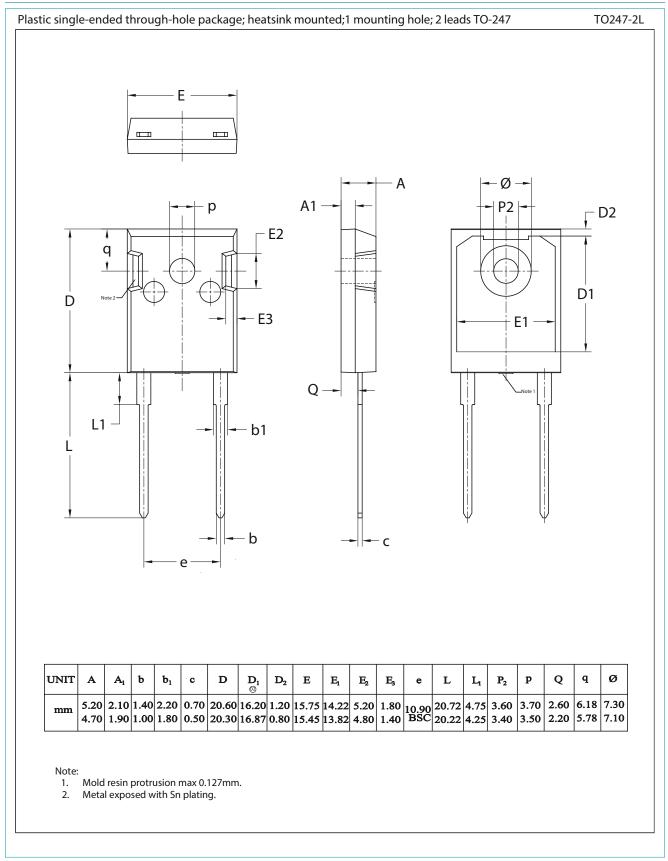
# WNSC2D30650W

Silicon Carbide Diode



### WNSC2D30650W Silicon Carbide Diode

## **11. Package outline**



WNSC2D30650W
Product data sheet

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# WNSC2D30650W

### Silicon Carbide Diode

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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